Technical Information Thyristor / Diode Modules

MS TD510





Key Parameters

| Vdrm / Vrrm | = 2200V |
|--------------------|----------|
| It(AV) | = 510A |
| Ітѕм | = 17000A |
| V _{T(TO)} | = 0.95V |
| rт | = 0.45mΩ |

Features

- Full blocking capability over wide temperature range
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Pressure contacts technology for high reliability
- UL Recognized, file no. E505556

ApplicationsPower Supplies

- DC motor control .
- **Controlled Rectifiers**
- AC switch

Ordering Information

| MS | TD | 510 | К | 22 | | |
|--|-----------------------------|-----------------|---|---|--|--|
| Fixed code | TD- Thyristor- Diode Module | Current Code | Technology K = Pressure Contact Technology | Voltage Code Code X 100 = V _{DRM} /V _{RRM} | | |
| Order Code MS TD510K22: 2200V VDRM, VRRM, Thyristor-Diode Module | | | | | | |
| Prepared by : ABA Date of Publication : 25.03.2015 | | | | | | |
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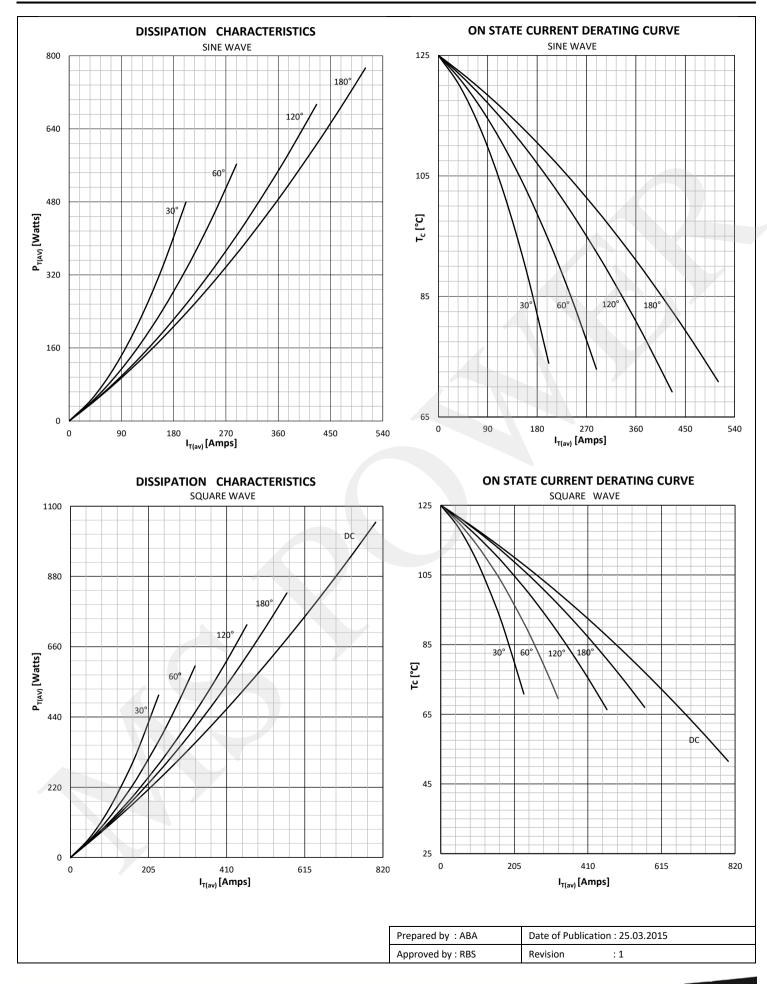
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| Symbol | Characteristic | Conditions | Тј [°С] | Value | Unit |
|-----------------|--|--|-------------|------------------------|------|
| BLOCKI | NG | | | | |
| V RRM | Repetitive peak reverse voltage | | 125 | 1800 - 2200 | V |
| V RSM | Non-repetitive peak reverse voltage | | 125 | 1900 - 2300 | V |
| V drm | Repetitive peak off-state voltage | | 125 | 1800 - 2200 | V |
| I RRM | Repetitive peak reverse current | V= V RRM | 125 | 80 | mA |
| DRM | Repetitive peak off-state current | V= V DRM | 125 | 80 | mA |
| CONDU | CTING | | | | |
| I T (AV) | Mean on state current | 180° sin ,50 Hz, T _c =70°C 180° sin ,50 Hz, T _c =85°C | | 510 432 | Α |
| I RMS | RMS on-state current | T _c =70°C | | 801 | А |
| | - | Sine wave, 10 ms | 25 | 17000 | А |
| I TSM | Surge on-state current | Without reverse voltage | 125 | 15000 | А |
| | | | 25 | 1445 x 10 ³ | A²s |
| l² t | l² t | Sine wave, 10 ms Without reverse voltage | 125 | 1125 x 10 ³ | A²s |
| Vт | On-state voltage | On-state current = 1500A | 25 | 1.47 | V |
| V T(TO) | Threshold voltage | | 125 | 0.95 | V |
| r T | On-state slope resistance | | 125 | 0.45 | mΩ |
| | · · | | | 0.10 | |
| SWITCH | | | 405 | 200 | A / |
| di/dt | Critical rate of rise of on-state current | | 125 | 200 | A/µs |
| dv/dt | Critical rate of rise of off-state voltage | $V_{DR} = V_{DRM}$ | 125 | 1000 | V/µs |
| GATE | | | | 222 | |
| l _{gt} | Gate trigger current | V _D =6V | 25 | 200 | mA |
| V _{gt} | Gate trigger voltage | V _D =6V | 25 | 3.0 | V |
| I _H | Holding current | V _D =6V, gate open circuit | 25 | 500 | mA |
| ΙL | Latching current | V _D =6V | 25 | 1500 | mA |
| MOUNT | ING | | | 0.0050 | |
| R th(j-c) | Thermal impedance, sin 180° | Junction to case, per arm per module | | 0.0650 0.0325 | °C/W |
| R th(j-c) | Thermal impedance, rec120° | Junction to case, per arm per module | | 0.074 0.037 | °C/W |
| R th(c-h) | Thermal impedance | Case to heatsink, per arm per module | | 0.02 0.01 | °C/W |
| Тj | Max. junction temperature | | | 125 | °C |
| T stg | Storage temperature | | | -40 150 | °C |
| VISOL | Insulation test voltage,RMS | F=50Hz, 1min | | 3.0 | KV |
| M1 | Mounting torque | | | 6 ± 15% | Nm |
| M2 | Terminal connection torque | | | 12 ± 15% | Nm |
| W | Weight (Approx.) | | | 1450 | gm |
| 91 * | File No. | | | E505556 | |
| | <i>#</i> | | | | |
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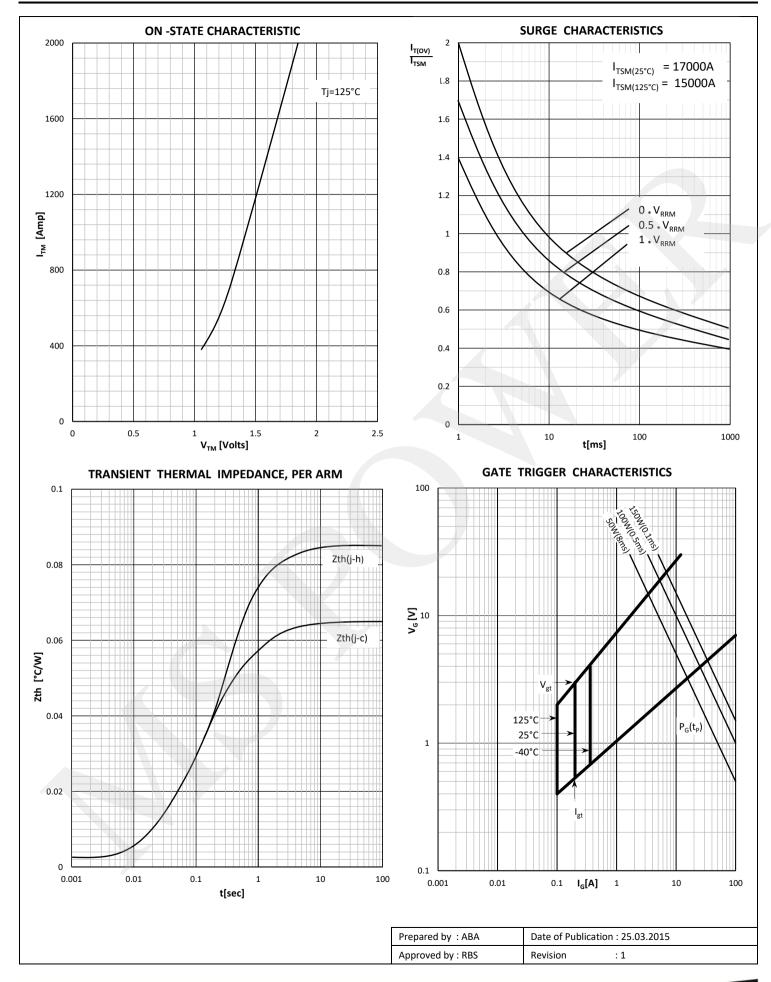
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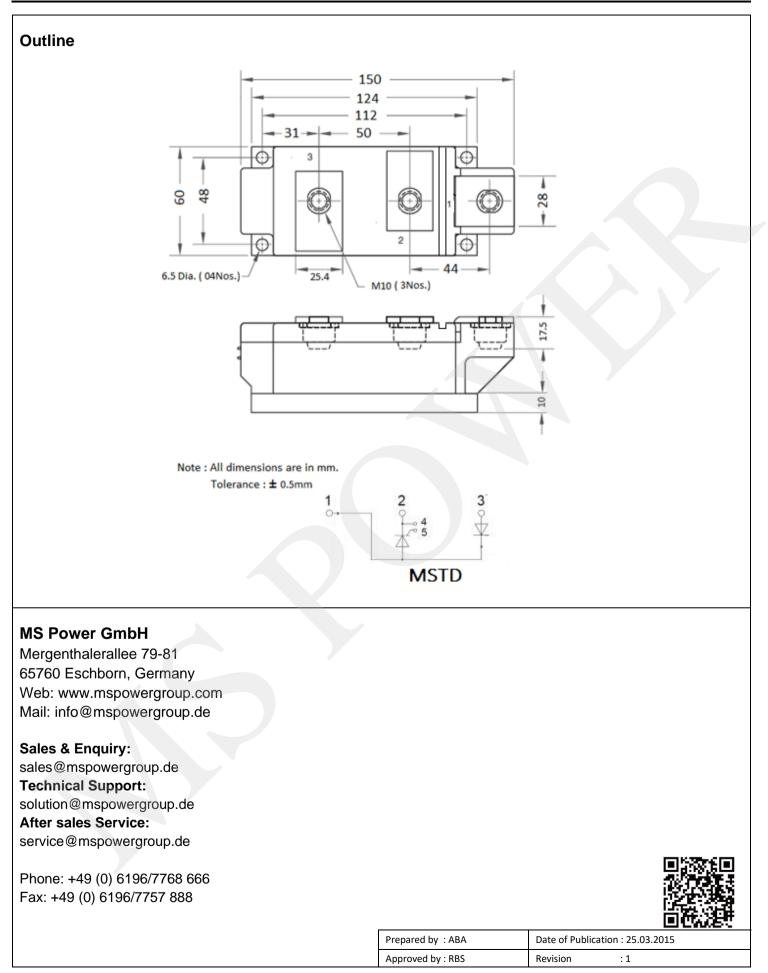




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